

Supporting Information

Binary flux-promoted formation of trigonal ZnIn₂S₄ layered crystals using ZnS-containing industrial waste and their photocatalytic performance for H₂ production†

Mirabbos Hojamberdiev^{a,*}, Yanfei Cai^a, Junie Jhon M. Vequizo^b, Mohammad Mansoob Khan^c, Ronald Vargas^d, Kunio Yubuta^e, Akira Yamakata^b, Katsuya Teshima^f, and Masashi Hasegawa^a

^a*Department of Materials Physics, Nagoya University, Furo-cho, Chikusa-ku, Nagoya 464-8603,
Japan*

^b*Graduate School of Engineering, Toyota Technological Institute, 2-12-1 Hisakata, Tempaku, Nagoya
468-8511, Japan*

^c*Chemical Sciences, Faculty of Science, Universiti Brunei Darussalam, Jalan Tungku Link, Gadong,
BE 1410, Brunei Darussalam*

^d*Departamento de Química, Universidad Simón Bolívar, Apartado 89000, Caracas 1080A, Venezuela*

^e*Institute for Materials Research, Tohoku University, 2-1-1 Katahira, Aoba-ku, Sendai 980-8577,
Japan*

^f*Center for Energy and Environmental Science, Shinshu University, 4-17-1 Wakasato, Nagano 380–
8553, Japan*

^{*}Corresponding author at: Department of Materials Physics, Nagoya University, Furo-cho, Chikusa-ku, Nagoya
464-8603, Aichi, Japan. E-mail address: hmirabbos@mp.pse.nagoya-u.ac.jp

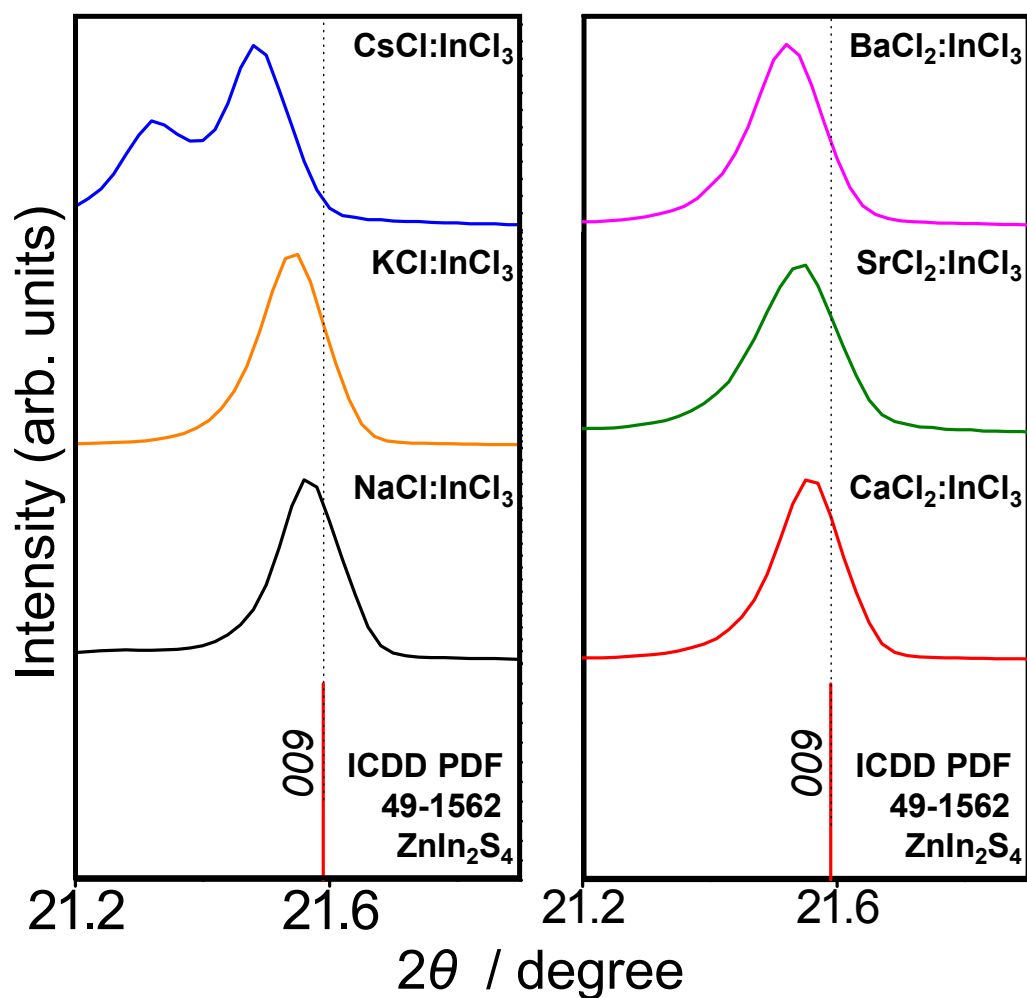


Figure S1. Enlarged XRD patterns of ZnIn₂S₄ crystals grown by a flux method at 800°C for 1 h under N₂ atmosphere with a 40 mol% solute concentration using different fluxes: NaCl:InCl₃, KCl:InCl₃, CsCl:InCl₃, CaCl₂:InCl₃, SrCl₂:InCl₃, and BaCl₂:InCl₃.

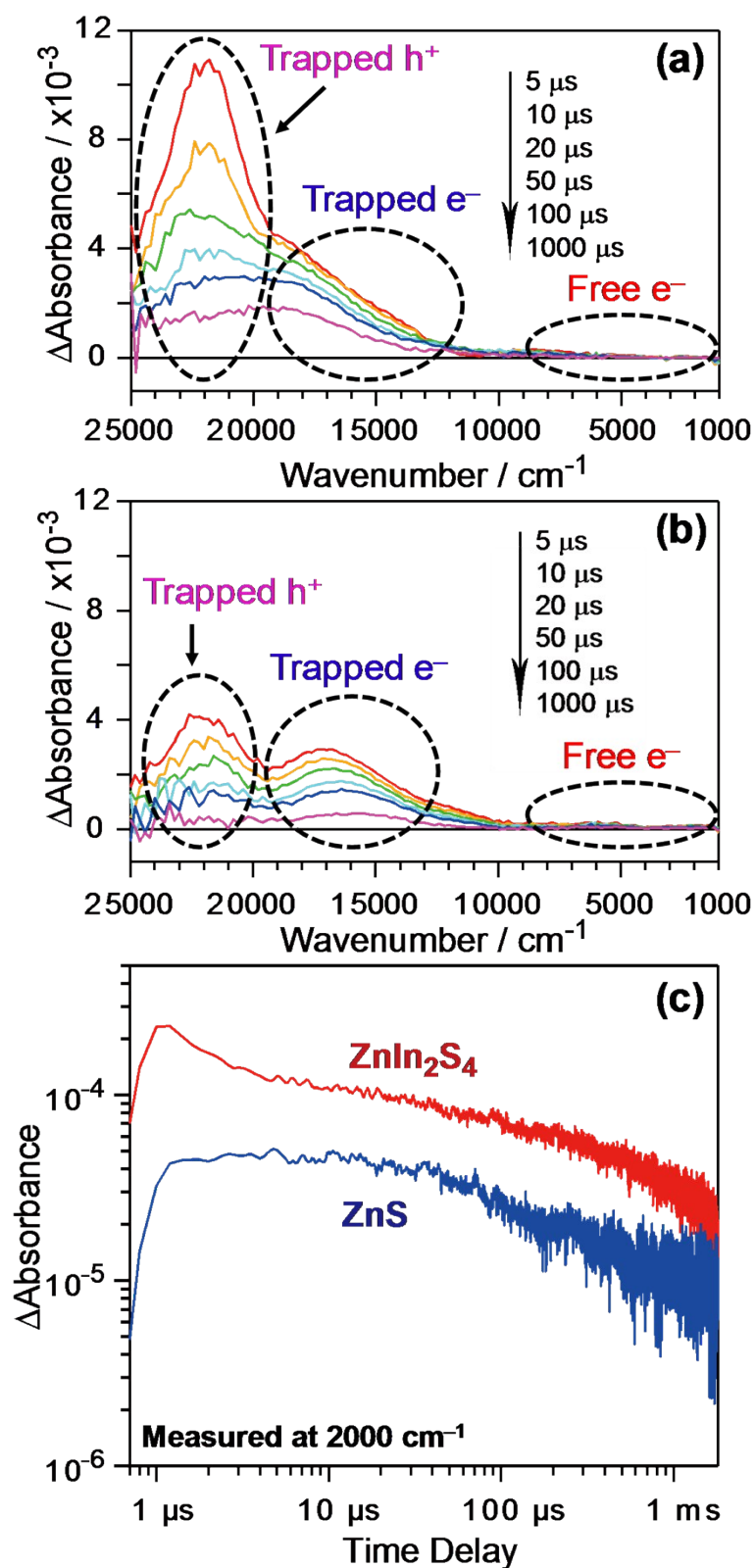


Figure S2. Transient absorption spectra of (a) ZnS and (b) ZnIn₂S₄ crystals grown by a flux method using KCl:InCl₃ flux excited by UV laser pulses (355 nm, 6-ns duration, 0.5 mJ per pulse, and 5 Hz) in nitrogen atmosphere. (c) Decay kinetics of photogenerated free electrons (2,000 cm^{-1}) in ZnS and ZnIn₂S₄ crystals grown by a flux method using KCl:InCl₃ flux excited by UV laser pulses.

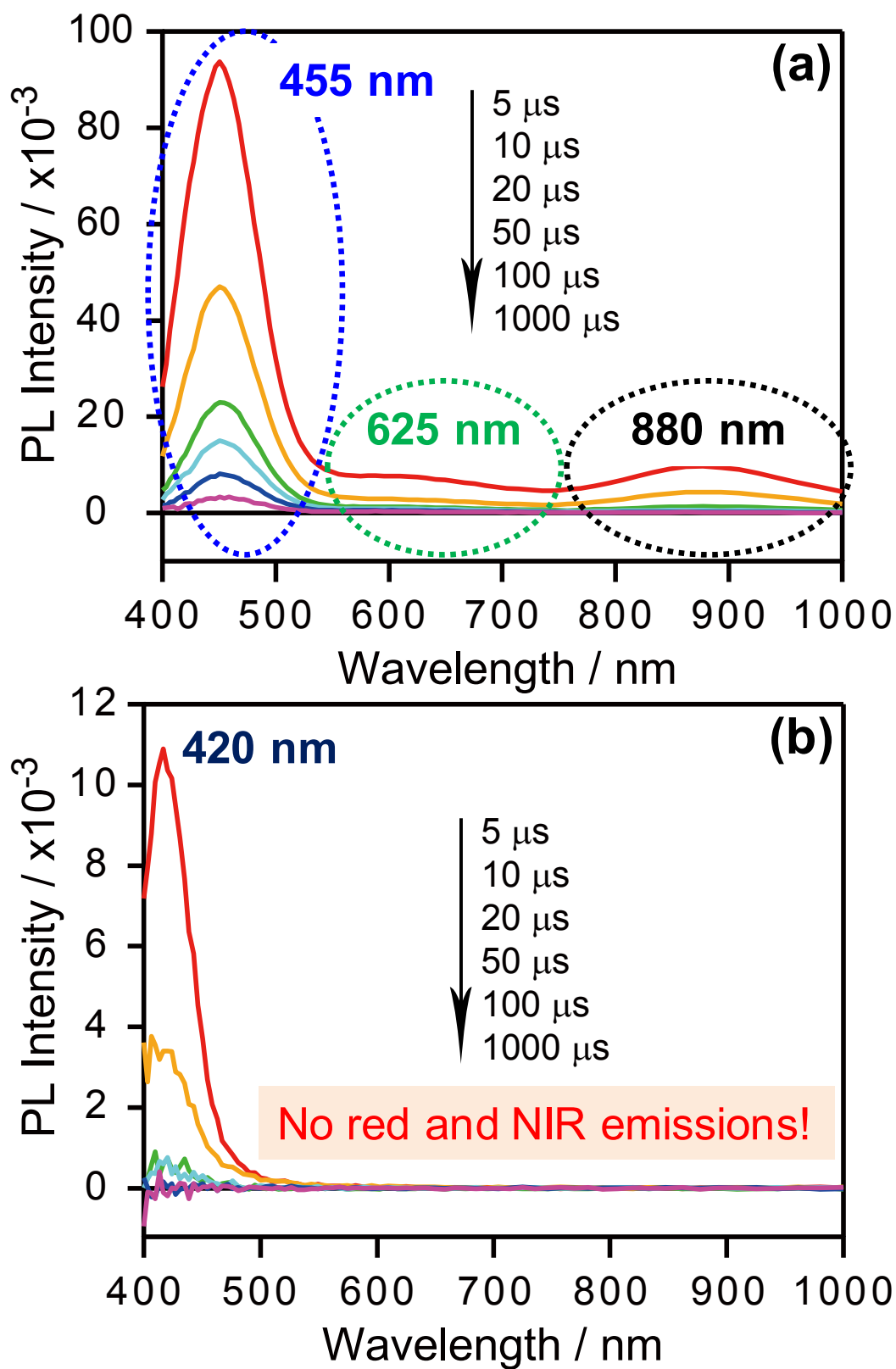


Figure S3. PL spectra of (a) ZnS and (b) ZnIn₂S₄ crystals grown by a flux method using KCl:InCl₃ flux.